# General Purpose Transistor (Isolated Dual Transistors)

# EMT1/UMT1N/IMT1A

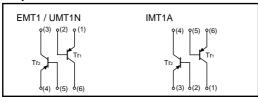
# Features

- 1) Two 2SA1037AK chips in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.

#### **●Structure**

Epitaxial planar type PNP silicon transistor

# ●Equivalent circuit



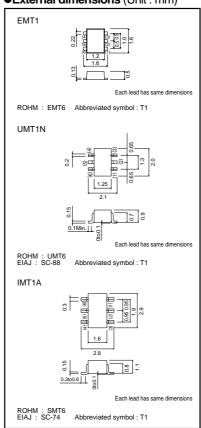
The following characteristics apply to both Tr<sub>1</sub> and Tr<sub>2</sub>.

# ● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-60	V	
Collector-emitter voltage		Vceo	-50	V	
Emitter-base voltage		V <sub>ЕВО</sub>	-6	V	
Collector current		lc	-150	mA	
Collector power dissipation	EMT1, UMT1N	Pc	150 (TOTAL)	*1 mW *2	
	IMT1A	PC	300 (TOTAL)		
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to +150	°C	

- \*1 120mW per element must not be exceeded.
- \*2 200mW per element must not be exceeded.

# ●External dimensions (Unit : mm)



# ●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage	ВУсво	-60	_	_	V	Ic = -50μA	
Collector-emitter breakdown voltage	BVceo	-50	-	-	V	Ic = -1mA	
Emitter-base breakdown voltage	ВУево	-6	-	-	٧	I <sub>E</sub> = -50μA	
Collector cutoff current	Ісво	-	-	-0.1	μΑ	Vcb = -60V	
Emitter cutoff current	ІЕВО	-	-	-0.1	μΑ	VEB = -6V	
Collector-emitter saturation voltage	VCE(sat)	-	-	-0.5	V	Ic/I <sub>B</sub> = -50mA/-5mA	
DC current transfer ratio	hfe	120	-	560	-	VcE = -6V, Ic = -1mA	
Transition frequency	f⊤	_	140	-	MHz	VcE = −12V, IE = 2mA, f = 100MHz	
Output capacitance	Cob	_	4	5	pF	Vсв = −12V, I∈ = 0A, f = 1МНz	

# Packaging specifications

	Package	Taping		
	Code	T2R	TR	T108
Туре	Basic ordering unit (pieces)	8000	3000	3000
EMT1		0	-	-
UMT1N		-	0	_
IMT1A		-		0

#### •Electrical characteristic curves

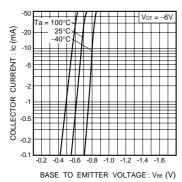


Fig.1 Grounded emitter propagation characteristics

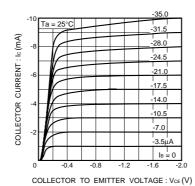


Fig.2 Grounded emitter output characteristics (I)

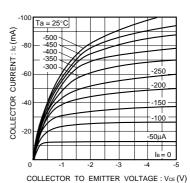


Fig.3 Grounded emitter output characteristics (II)

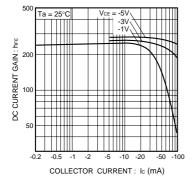


Fig.4 DC current gain vs. collector current ( I )

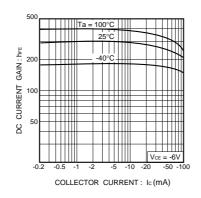


Fig.5 DC current gain vs. collector current ( II )

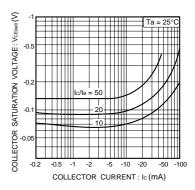


Fig.6 Collector-emitter saturation voltage vs. collector current ( I )

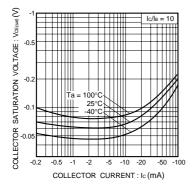


Fig.7 Collector-emitter saturation voltage vs. collector current ( II )

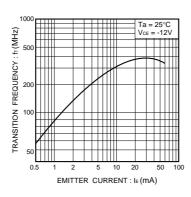


Fig.8 Gain bandwidth product vs. emitter current

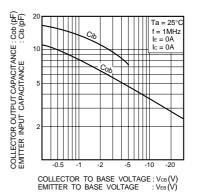


Fig.9 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage

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